DC COMPONENTS CO., LTD.

RECTIFIER SPECIALISTS

RL251 THRU RL257

TECHNICAL SPECIFICATIONS OF SILICON RECTIFIER

VOLTAGE RANGE - 50 to 1000 Volts CURRENT - 2.5 Amperes

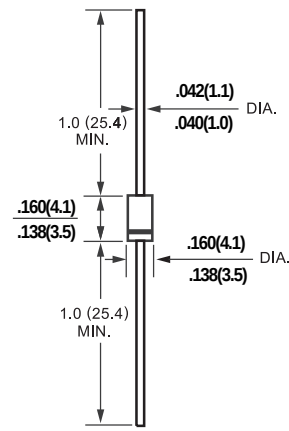
FEATURES

* Low cost
* Low leakage
* Low forward voltage drop
* High current capability

MECHANICAL DATA

* Case: Molded plastic
* Epoxy: UL 94V-0 rate flame retardant
* Lead: MIL-STD-202E, Method 208 guaranteed
* Polarity: Color band denotes cathode end
* Mounting position: Any
* Weight: 0.54 gram

R-3



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

		SYMBOL	RL251	RL252	RL253	RL254	RL255	RL256	RL257	UNITS
Maximum Recurrent Peak Reverse Voltage		V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage		V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T_A = 75°C		I_O	2.5							Amps
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		I_{FSM}	150							Amps
Maximum Instantaneous Forward Voltage at 2.5A DC		V_F	1.0							Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage	@T_A = 25°C	I_R	5.0							µAmps
	@T_A = 100°C		50							
Maximum Full Load Reverse Current Average, Full Cycle .375*(9.5mm) lead length at T_L = 75°C			30							µAmps
Typical Junction Capacitance (Note)		C_J	35							pF
Typical Thermal Resistance		$R\theta_{JA}$	35							°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-65 to + 175							°C

NOTES : Measured at 1 MHz and applied reverse voltage of 4.0 volts

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EXIT